NSN 5961-01-525-5105

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-525-5105 **Inclosure Material:** Plastic **Overall Length:** 58.0 millimeters **Overall Diameter:** Between 4.8 millimeters and 5.3 millimeters **End Application:** Misc. Electric plant **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 working peak reverse voltage **Current Rating Per Characteristic:** 0.50 milliamperes collector current, dc major **Special Features:** Low power loss, high efficiency. High surge capability. Surge overload rating to 150a peak. Plastic material: ul flammability classification rating 94v-0. **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No